

Amendments to the Claims:

This listing of claims replaces all prior versions and listings of claims in the application:

Listing of Claims:

1. (Original) A display device in which a thin film transistor is disposed on an insulative substrate, said thin film transistor comprising:
 - a first gate electrode; a gate insulating film; a semiconductor film which is formed on said gate insulating film and which has a channel;
 - a insulating film;
 - a display electrode connected to a source which is formed in said semiconductor film, said display electrode being elongated so as to extend above said channel of said thin film transistor, andwherein a second gate electrode formed between said first gate electrode and said display electrode.
2. (Original) A display device in which a thin film transistor is disposed on an insulative substrate, said thin film transistor comprising:
 - a first gate electrode; a gate insulating film; a semiconductor film which is formed on said gate insulating film and which has a channel;
 - a insulating film;
 - a display electrode connected to a source which is formed in said semiconductor film, said display electrode being elongated so as to extend above said channel of said thin film transistor; anda second gate electrode formed between said first gate electrode and said display electrode,

wherein said second gate electrode is connected with said first gate electrode.

3. (Original) A display device according to claim 2, wherein said second gate electrode is formed so as to be faced with said first gate electrode through said insulating film.
4. (Original) A display device according to claim 3, wherein said display electrode is rectangular.
5. (Original) A display device according to claim 1, wherein said channel is covered with a stopper insulating film.
6. (Original) A display device according to claim 5, wherein said stopper insulating film is made of an SiO_2 film.
7. (Original) A display device according to claim 5, wherein said stopper insulating film is made of a two-layered film of SiN and organic film.
8. (Original) A display device according to claim 1, wherein said first gate electrode is a double gate structured electrode divided above the channel.
9. (Original) A display device according to claim 8, wherein said second gate electrode is a double gate structured electrode divided corresponding to said first gate electrode.
10. (Original) A display device according to claim 1, wherein said display electrode is a reflective display electrode which is made of a reflective material.
11. (Original) A display device according to claim 10, wherein said reflective display electrode is made of Al-Nd alloy.

12. (Original) A display device according to claim 1, wherein said display electrode is an electrode used in a liquid display device.

13. (Original) A display device according to claim 1, wherein a light emitting layer is formed on said display electrode, and said display electrode used in an organic electro luminescent device.

14. (Currently Amended) A display device according to claim 1, wherein said thin film transistor further ~~comprising~~ comprises:

~~a storage capacity electrode~~ a holding capacitance electrode;
wherein a capacitance electrode connected to the source region and the holding
capacitance electrode are arranged relative to each other to ~~which~~ constitute a capacitance; and
wherein the holding capacitance electrode ~~one side of the storage capacity electrode is~~
made of a same material ~~of~~ as the first gate electrode.

15. (Original) A display device according to claim 2, wherein a light omitting layer is formed on said display electrode, and said display electrode used in an organic electro luminescent device.

16. (Currently Amended) A display device according to claim 2, wherein said thin film transistor further ~~comprising~~ comprises:

~~a storage capacity electrode~~ a holding capacitance electrode;
wherein a capacitance electrode connected to the source region and the holding
capacitance electrode are arranged relative to each other to ~~which~~ constitute a capacitance; and
wherein the holding capacitance electrode ~~one side of the storage capacity electrode is~~
made of a same material ~~of~~ as the first gate electrode.

17. (Original) A display device comprising:
an insulative substrate;
a thin film transistor including a gate electrode, a gate insulating film and a channel region;
a display electrode connected to one of a source region of the thin film transistor and a drain region of the thin film transistor, said display electrode being extended above the channel region of the thin film transistor;
an electrode provided between the channel region of the thin film transistor and the display electrode,
wherein the electrode is connected to the gate electrode.
18. (Original) The display device according to claim 17, wherein said display electrode is a reflective display electrode made of a reflective material.
19. (Original) A display device according to claim 17, wherein a light emitting layer is formed on said display electrode, and said display electrode used in an organic electro luminescent device.
20. (Currently Amended) A display device according to claim 17, further comprising:
~~a storage capacity electrode~~ a holding capacitance electrode;
wherein a capacitance electrode connected to the source region and the holding capacitance electrode are arranged relative to each other to which constitute a capacitance; and
wherein the holding capacitance electrode ~~one side of the storage capacity electrode~~ is made of a same material of as the first gate electrode.
21. (Original) A display device comprising:
an insulative substrate;

a thin film transistor including a gate electrode, a gate insulating film and a channel region;

a display electrode connected to one of a source region of the thin film transistor and a drain region of the thin film transistor, said display electrode being extended above the channel region of the thin film transistor;

an electrode provided between the channel region of the thin film transistor and the display electrode,

wherein a gate voltage is applied to the electrode.

22. (Original) The display device according to claim 21, wherein said display electrode is a reflective display electrode made of a reflective material.

23. (Original) A display device according to claim 22, wherein a light emitting layer is formed on said display electrode, and said display electrode used in an organic electro luminescent device.

24. (Currently Amended) A display device according to claim 22, further comprising:
~~a storage capacity electrode~~ a holding capacitance electrode line;
wherein a capacitance electrode connected to the source region and the holding electrode line are arranged relative to each other to which constitute a capacitance; and
wherein the holding capacitance electrode ~~one side of the storage capacity electrode~~ is made of a same material of as the first gate electrode.